



DDTB (LO-R1) C

PNP PRE-BIASED 500 mA SURFACE MOUNT TRANSISTOR

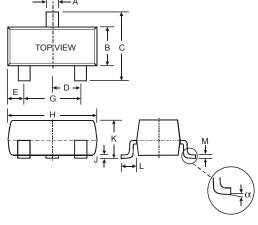
Features

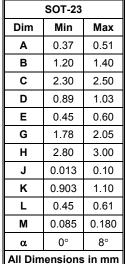
- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTD)
- · Built-In Biasing Resistors
- Lead, Halogen and Antimony Free, RoHS Compliant "Green" Device (Notes 1 and 3)

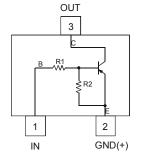
Mechanical Data

- Case: SOT-23
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminal Connections: See Diagram
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Marking Information: See Table Below & Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)

| P/N | R1 (NOM) | R2 (NOM) | Type Code |
|-----------|-------------------|----------|-----------|
| DDTB122LC | 0.22KΩ | 10KΩ | P75 |
| DDTB142JC | 0.47 K Ω | 10KΩ | P76 |
| DDTB122TC | 0.22 K Ω | OPEN | P77 |
| DDTB142TC | 0.47ΚΩ | OPEN | P78 |







Schematic and Pin Diagram

Maximum Ratings @T_A = 25°C unless otherwise specified

| Characteristic | | Symbol | Value | Unit | |
|---|------------------------|-----------------------------------|----------------------|------|--|
| Supply Voltage, (3) to (2) | | Vcc | -50 | V | |
| Input Voltage, (1) to (2) | DDTB122LC DDTB142JC | V _{IN} | +5 to -6 +5 to -6 | V | |
| Input Voltage, (2) to (1) | DDTB122TC DDTB142TC | V _{EBO (MAX)} | -5 | V | |
| Output Current | All | I _C | -500 | mA | |
| Power Dissipation | (Note 2) | P _D | 200 | mW | |
| Thermal Resistance, Junction to Ambient Air | (Note 2) | $R_{	hetaJA}$ | 625 | °C/W | |
| Operating and Storage Temperature Range | | T _J , T _{STG} | -55 to +150 | °C | |

Notes:

- 1. No purposefully added lead. Halogen and Antimony Free.
- No purpose taily added lead. Hatelger and Atthinory Free.
 Mounted on FR4 PC Board with recommended pad layout at http://www.diodes.com/datasheets/ap02001.pdf.
- Product manufactured with Data Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb₂O₃ Fire Retardants.



Electrical Characteristics @TA = 25°C unless otherwise specified R1, R2 Types

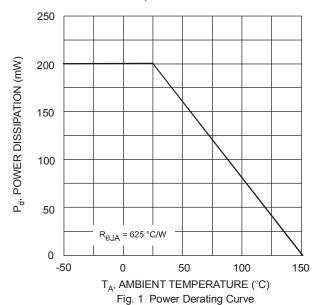
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|-------------------------------------|------------------------|---------------------|--------------|--|------------|----------------|---|
| Input Voltage | DDTB122LC DDTB142JC | V _{I(off)} | -0.3 -0.3 | _ | _ | V | V _{CC} = -5V, I _O = -100μA |
| | DDTB122LC DDTB142JC | | | $V_O = -0.3V$, $I_O = -20mA$ $V_O = -0.3V$, $I_O = -20mA$ | | | |
| Output Voltage | | $V_{O(on)}$ | _ | _ | -0.3V | V | $I_{O}/I_{I} = -50$ mA/-2.5mA |
| Input Current DDTB122LC DDTB142JC | | l _l | | _ | -28 -13 | mA | V _I = -5V |
| Output Current | | I _{O(off)} | _ | _ | -0.5 | μА | $V_{CC} = -50V, V_I = 0V$ |
| DC Current Gain DDTB122LC DDTB142JC | | G _l | 56 56 | _ | | _ | V _O = -5V, I _O = -50mA |
| Gain-Bandwidth Product* | | f⊤ | | 200 | | MHz | V _{CE} = -10V, I _E = -5mA, f = 100MHz |

^{*} Transistor - For Reference Only

Electrical Characteristics @TA = 25°C unless otherwise specified R1- Only Types

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|-------------------|----------------------|------------|------------|--------------|---------------------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -50 | _ | _ | V | $I_{C} = -50 \mu A$ | |
| Collector-Emitter Breakdown Voltage | | BV _{CEO} | -40 | _ | _ | V | I _C = -1mA |
| Emitter-Base Breakdown Voltage DDTB122TC DDTB142TC | | BV _{EBO} | -5 | _ | | ٧ | $I_E = -50\mu A$ $I_E = -50\mu A$ |
| Collector Cutoff Current | | I _{CBO} | _ | _ | -0.5 | μА | V _{CB} = -50V |
| Emitter Cutoff Current DDTB122TC DDTB142TC | | I _{EBO} | _ | _ | -0.5 -0.5 | μА | V _{EB} = -4V |
| Collector-Emitter Saturation Voltage | | V _{CE(sat)} | _ | _ | -0.3 | V | $I_C = -50$ mA, $I_B = -2.5$ mA |
| DC Current Transfer Ratio DDTB122TC DDTB142TC | | h _{FE} | 100 100 | 250 250 | 600 600 | | I _C = -5mA, V _{CE} = -5V |
| Gain-Bandwidth Product* | | f⊤ | _ | 200 | | MHz | V _{CE} = -10V, I _E = 5mA, f = 100MHz |

^{*} Transistor - For Reference Only



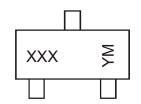


Ordering Information (Note 4)

| Device | Packaging | Shipping |
|---------------|-----------|------------------|
| DDTB122LC-7-F | SOT-23 | 3000/Tape & Reel |
| DDTB142JC-7-F | SOT-23 | 3000/Tape & Reel |
| DDTB122TC-7-F | SOT-23 | 3000/Tape & Reel |
| DDTB142TC-7-F | SOT-23 | 3000/Tape & Reel |

Notes: 4. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

Marking Information



XXX = Product Type Marking Code, See Table on Page 1

YM = Date Code Marking Y = Year ex: T = 2006 M = Month ex: 9 = September

Date Code Key

| Year | 200 | 6 2007 | | | 2008 | | 2009 | | | 2011 | 2012 | |
|-------|-----|--------|-----|-----|------|-----|------|-----|-----|------|------|-----|
| Code | Т | | U | | V W | | Х | | Υ | Z | | |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | | ^ | ^ | | - | ^ | _ | 0 | ^ | ^ | N.I. | _ |

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